



MILITARY DATA SHEET

MN54F240-X REV 1A0

Original Creation Date: 03/29/96
Last Update Date: 07/30/96
Last Major Revision Date: 03/29/96

OCTAL BUFFER/LINE DRIVER WITH TRI-STATE OUTPUTS

General Description

The F240 is a octal buffer and line driver designed to be employed as a memory and address driver, clock driver and bus-oriented transmitter/receiver which provides improved PC and board density.

Industry Part Number

54F240

NS Part Numbers

54F240-DMQB
54F240-FMQB
54F240-LMQB

Prime Die

M240

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp	Description	Temp (°C)
1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

Features

- 3-State Outputs Drive Bus Lines or Buffer Address Registers
- Outputs Sink 48 mA
- 12mA Source Current
- Input Clamp Diodes Limit High-Speed Termination Effects

(Absolute Maximum Ratings)

(Note 1)

Storage Temperature	-65 C to +150 C
Ambient Temperature under Bias	-55 C to +125 C
Junction Temperature under Bias	-55 C to +175 C
Vcc Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30mA to +5.0mA
Voltage Applied to Output in HIGH State (with Vcc=0V)	
Standard Output	-0.5V to Vcc
TRI-STATE Output	-0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated Iol(mA)
ESD Last Passing Voltage (Min)	4000V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Commercial	0 C to +70 C
Military	-55 C to +125 C
Supply Voltage	
Military	+4.5V to +5.5V
Commercial	+4.5V to +5.5V

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
DC: 4.5V to 5.5V, -55 C to 125 C

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
IIH	Input High Current	VCC=5.5V, VM=2.7V, VINH=5.5V, VINL=0.0V	1, 3	INPUTS		20	uA	1, 2, 3
IBVI	Input High Current	VCC=5.5V, VM=7.0V, VINH=5.5V, VINL=0.0V	1, 3	INPUTS		100	uA	1, 2, 3
IIL	Input LOW Current	VCC=5.5V, VM=0.5V, VINL=0.0V, VINH=5.5V	1, 3	INPUTS		-1.0	mA	1, 2, 3
VOLB	Output LOW Voltage	VCC=4.5V, VIL=0.8V, VIH=2.0V, IOLB=48mA	1, 3	OUTPUTS		.55	V	1, 2, 3
VOH3	Output HIGH Voltage	VCC=4.5V, VIL=0.8V, IOH3=-3.0mA	1, 3	OUTPUTS	2.4		V	1, 2, 3
VOHB	Output HIGH Voltage	VCC=4.5V, VIL=0.8V, IOHB=-12mA	1, 3	OUTPUTS	2.0		V	1, 2, 3
IOS	Short-Circuit Current	VCC=5.5V, VINL=0.0V, VM=0.0V	1, 3	OUTPUTS	-100	-225	mA	1, 2, 3
VCD	Input Clamp Diode Voltage	VCC=4.5V, IM=-18mA, VINH=5.5V	1, 3	INPUTS		-1.2	V	1, 2, 3
ICCH	Supply Current	VCC=5.5V, VINL=0.0V	1, 3	VCC		29	mA	1, 2, 3
ICCL	Supply Current	VCC=5.5V, VINH=5.5V, VINL=0.0V	1, 3	VCC		75	mA	1, 2, 3
ICCZ	Supply Current	VCC=5.5V, VINH=5.5V	1, 3	VCC		63	mA	1, 2, 3
IOZH	Output Leakage Current	VCC=5.5V, VM=2.7V, VIH=2.0V, VINH=5.5V	1, 3	OUTPUTS		50	uA	1, 2, 3
IOZL	Output Leakage Current	VCC=5.5V, VM=2.7V, VIH=2.0V, VINL=0.0V	1, 3	OUTPUTS		-50	uA	1, 2, 3

Electrical Characteristics

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
 AC: RL=500 OHMS, CL=50pf TR=2.5ns, TF=2.5ns SEE AC FIGS

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
tpLH	Propagation Delay	VCC=5.0V @25C VCC=4.5V & 5.5V @-55/125C	2, 4	In to On	3.0	7.0	ns	9
			2, 4	In to On	3.0	9.0	ns	10, 11
tpHL	Propagation Delay	VCC=5.0V @25C VCC=4.5V & 5.5V @-55/125C	2, 4	In to On	2.0	4.7	ns	9
			2, 4	In to On	2.0	6.0	ns	10, 11
tpZH	Output Enable Time	VCC=5.0V @25C VCC=4.5V & 5.5V @-55/125C	2, 4	OE to On	2.0	5.2	ns	9
			2, 4	OE to On	2.0	6.5	ns	10, 11
tpZL	Output Enable Time	VCC=5.0V @25C VCC=4.5V & 5.5V @-55/125C	2, 4	OE to On	4.0	9.0	ns	9
			2, 4	OE to On	4.0	10.5	ns	10, 11
tpHZ	Output Disable Time	VCC=5.0V @25C VCC=4.5V & 5.5V @-55/125C	2, 4	OE to On	2.0	5.3	ns	9
			2, 4	OE to On	2.0	6.5	ns	10, 11
tpLZ	Output Disable Time	VCC=5.0V @25C VCC=4.5V & 5.5V @-55/125C	2, 4	OE to On	2.0	8.0	ns	9
			2, 4	OE to On	2.0	12.5	ns	10, 11

Note 1: Screen tested 100% on each device at -55 C, +25 C & +125 C temperature, Subgroups A1, 2, 3, 7 & 8.

Note 2: Screen tested 100% on each device at +25 C temperature only, Subgroup A9.

Note 3: Sample tested (Method 5005, Table 1) on each MFG. lot at +25 C, +125 C & -55 C temp., Subgroup A1, 2, 3, 7 & 8.

Note 4: Sample tested (Method 5005, Table 1) on each MFG. lot at +25 C Subgroup A9 & periodically at +125 C & -55 C temp., Subgroups 10 & 11.